Power Transistors

Panasonic

2SC5739

Silicon NPN epitaxial planar type

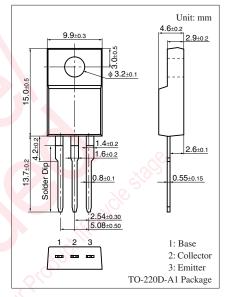
Power supply for Audio & Visual equipments such as TVs and VCRs Industrial equipments such as DC-DC converters

Features

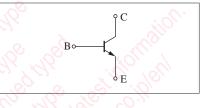
- High-speed switching (t_{stg}: storage time/t_f: fall time is short)
- \bullet Low collector-emitter saturation voltage $V_{\mbox{\scriptsize CE(sat)}}$
- Superior forward current transfer ratio h_{FE} linearity
- TO-220D built-in: Excellent package with withstand voltage 5 kV guaranteed

Parameter	Symbol	Rating	Unit				
Collector-base voltage (Emitter open)	V _{CBO}	60	v				
Collector-emitter voltage (Base open)	V _{CEO}	60	V				
Emitter-base voltage (Collector open)	V _{EBO}	6	V				
Collector current	I _C	3	A				
Peak collector current *	I _{CP}	6	A				
Collector power dissipation	P _C	20	W				
$T_a = 25^{\circ}C$		2.0	S X				
Junction temperature	Tj	150	°C				
Storage temperature	T _{stg}	-55 to +150	°C				





Internal Connection



Note) *: Non-repetitive peak collector current

Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

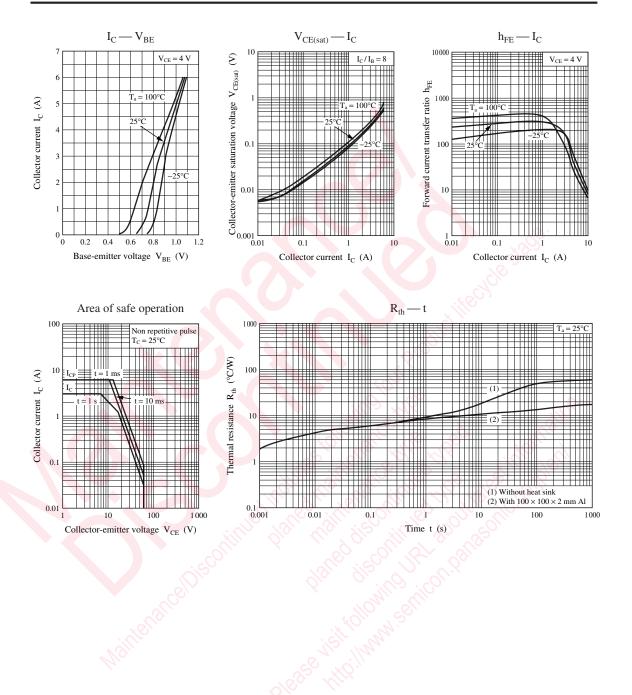
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	60			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 60 \text{ V}, I_E = 0$			100	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 60 \text{ V}, I_B = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 6 V, I_C = 0$			1	mA
Forward current transfer ratio	h _{FE1} *	$V_{CE} = 4 V, I_C = 1 A$	120		320	_
	h _{FE2}	$V_{CE} = 4 V, I_C = 3 A$	40			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 3$ A, $I_{\rm B} = 0.375$ A			0.5	V
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, I_C = 0.1 \text{ A}, f = 10 \text{ MHz}$		180		MHz
Turn-on time	t _{on}	$I_C = 1$ A, Resistance loaded		0.2	0.3	μs
Storage time	t _{stg}	$I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A}$		0.55	0.70	μs
Fall time	t _f	$V_{CC} = 50 V$		0.10	0.15	μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Q	Р
h _{FE1}	120 to 250	160 to 320

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